



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



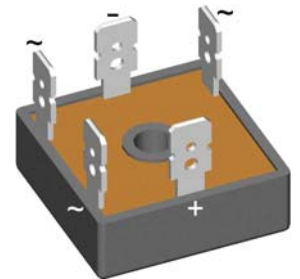
## Standard Rectifier Module


<b>3~ Rectifier</b>	
$V_{RRM}$	= 1400 V
$I_{DAV}$	= 27 A
$I_{FSM}$	= 550 A

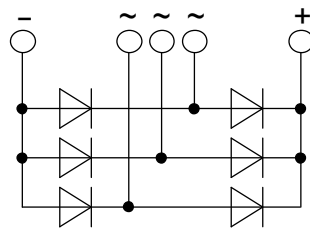
### 3~ Rectifier Bridge

Part number

VUO36-14NO8



 E72873



#### Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

#### Applications:

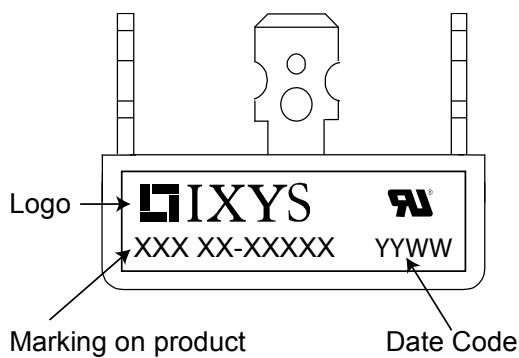
- Diode for main rectification
- For three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

#### Package: FO-B

- Industry standard outline
- RoHS compliant
- ¼" fast-on terminals
- Easy to mount with one screw

Rectifier				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
$V_{RSM}$	max. non-repetitive reverse blocking voltage					1500	V
$V_{RRM}$	max. repetitive reverse blocking voltage					1400	V
$I_R$	reverse current	$V_R = 1400$ V		$T_{VJ} = 25^\circ\text{C}$		40	$\mu\text{A}$
		$V_R = 1400$ V		$T_{VJ} = 150^\circ\text{C}$		1.5	mA
$V_F$	forward voltage drop	$I_F = 15$ A		$T_{VJ} = 25^\circ\text{C}$		1.04	V
						1.23	V
		$I_F = 45$ A		$T_{VJ} = 125^\circ\text{C}$		0.93	V
						1.18	V
$I_{DAV}$	bridge output current	$T_C = 85^\circ\text{C}$ rectangular	$d = \frac{1}{3}$	$T_{VJ} = 150^\circ\text{C}$		27	A
$V_{FO}$	threshold voltage			$T_{VJ} = 150^\circ\text{C}$		0.76	V
$r_F$	slope resistance						9.1
$R_{thJC}$	thermal resistance junction to case					7	K/W
$R_{thCH}$	thermal resistance case to heatsink				1		K/W
$P_{tot}$	total power dissipation			$T_C = 25^\circ\text{C}$		17	W
$I_{FSM}$	max. forward surge current	$t = 10$ ms; (50 Hz), sine		$T_{VJ} = 45^\circ\text{C}$		550	A
							595
		$t = 8,3$ ms; (60 Hz), sine		$T_{VJ} = 150^\circ\text{C}$		470	A
							505
$I^2t$	value for fusing	$t = 10$ ms; (50 Hz), sine		$T_{VJ} = 45^\circ\text{C}$		1.52	kA <sup>2</sup> s
							1.48
		$t = 8,3$ ms; (60 Hz), sine		$T_{VJ} = 150^\circ\text{C}$		1.11	kA <sup>2</sup> s
							1.06
$C_J$	junction capacitance	$V_R = 400$ V; $f = 1$ MHz		$T_{VJ} = 25^\circ\text{C}$		18	pF

Package FO-B		Ratings				
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$I_{RMS}$	RMS current	per terminal			100	A
$T_{stg}$	storage temperature		-40		125	°C
$T_{VJ}$	virtual junction temperature		-40		150	°C
<b>Weight</b>				20		g
$M_D$	mounting torque		1.8		2.2	Nm
$d_{Spp/App}$	creepage distance on surface   striking distance through air	terminal to terminal	9.0	7.0		mm
$d_{Spb/Apb}$		terminal to backside	10.0	10.0		mm
$V_{ISOL}$	isolation voltage	t = 1 second	3000			V
		t = 1 minute 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA	2500			V

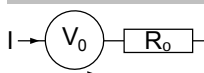


Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	VUO36-14NO8	VUO36-14NO8	Box	50	465151

### Equivalent Circuits for Simulation

\* on die level

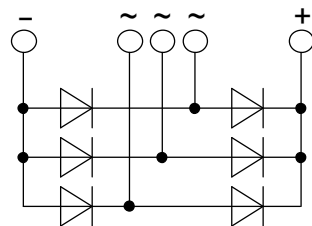
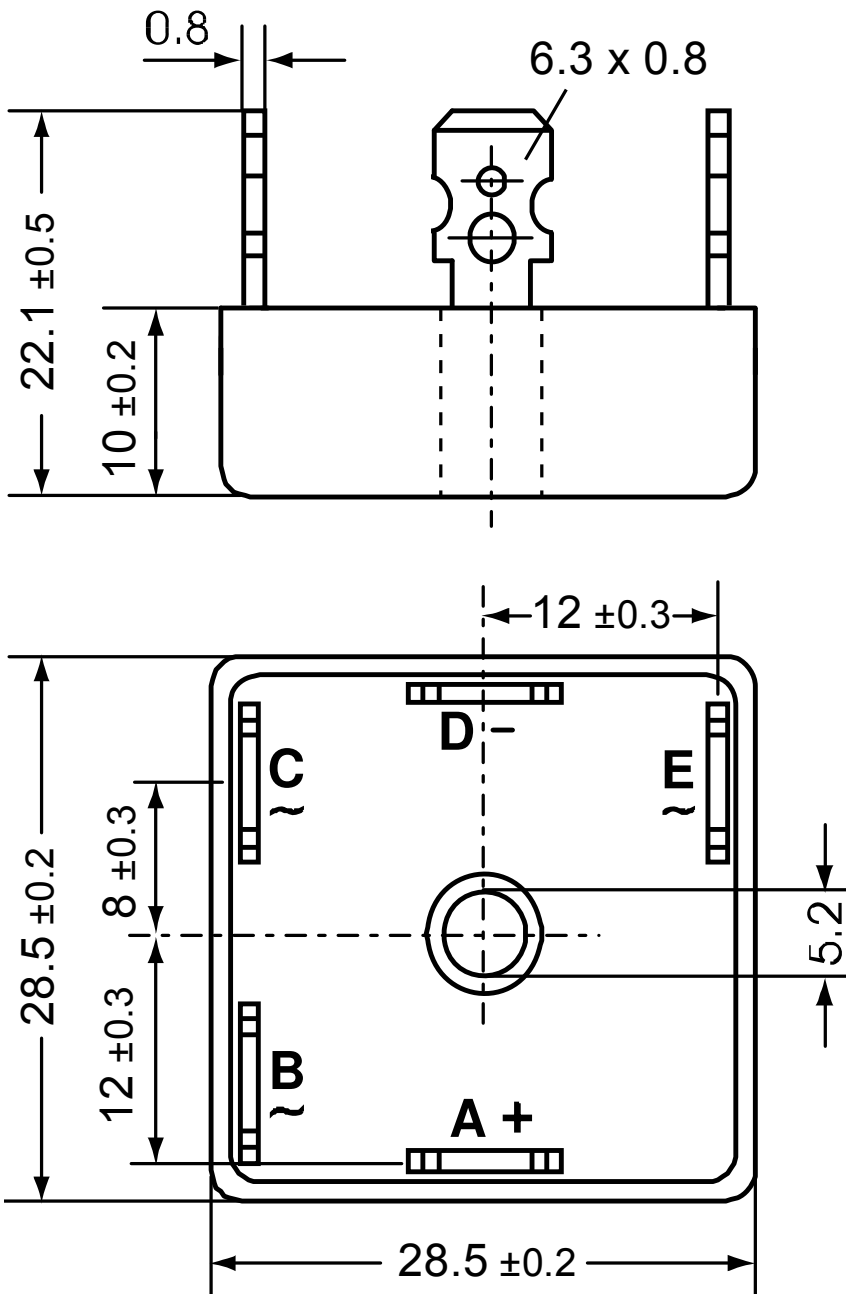
$T_{VJ} = 150^\circ\text{C}$



Rectifier

$V_{0\max}$	threshold voltage	0.76	V
$R_{0\max}$	slope resistance *	7.9	mΩ

Outlines FO-B



**Rectifier**

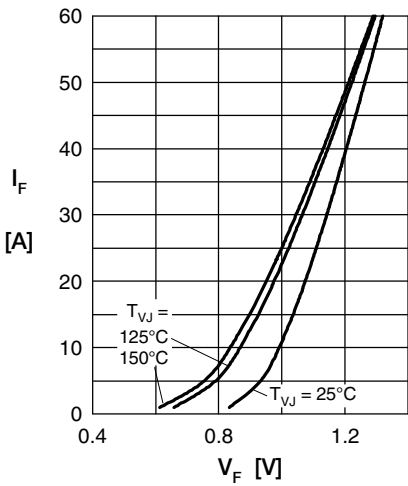


Fig. 1 Forward current vs. voltage drop per diode

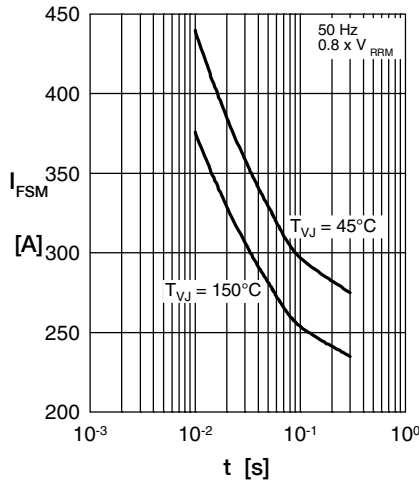


Fig. 2 Surge overload current vs. time per diode

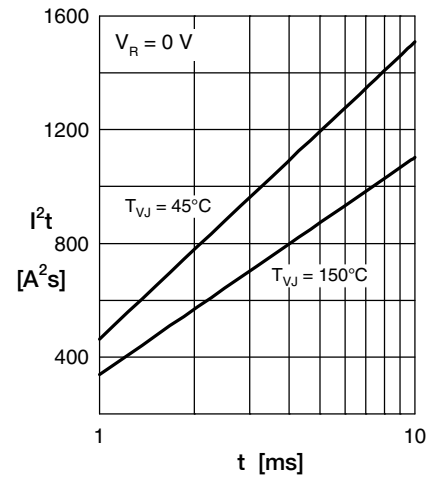


Fig. 3  $I^2t$  vs. time per diode

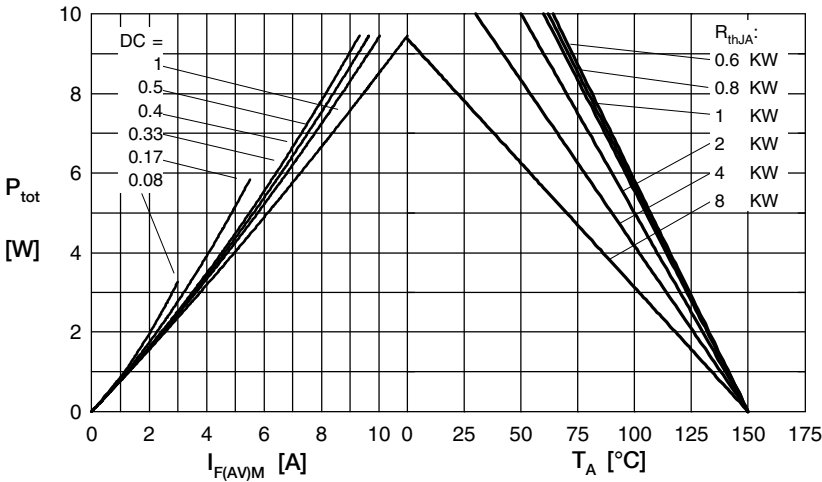


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

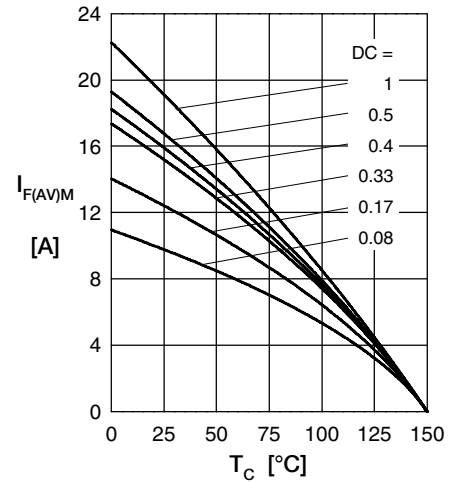


Fig. 5 Max. forward current vs. case temperature per diode

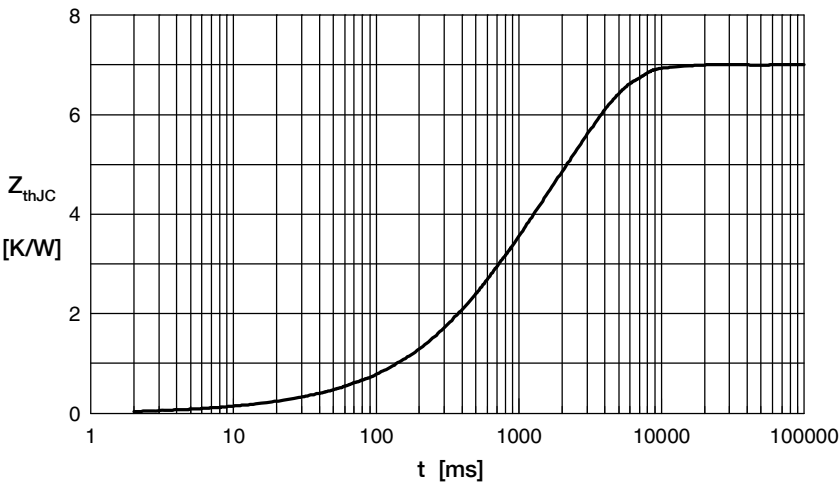


Fig. 6 Transient thermal impedance junction to case vs. time per diode

Constants for  $Z_{thJC}$  calculation:

i	$R_{th}$ (K/W)	$t_i$ (s)
1	0.040	0.005
2	0.150	0.030
3	1.710	0.400
4	5.100	2.300